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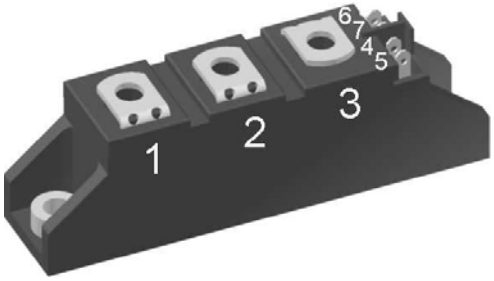
# Thyristor Module

$V_{RRM}$ = 2x 1600 V
$I_{TAV}$ = 110 A
$V_T$ = 1.21 V

## Phase leg

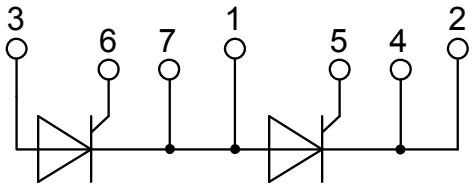
**Part number**

MCMA110P1600TA




Backside: isolated

E72873




**Features / Advantages:**

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

**Applications:**

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

**Package:** TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

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| Thyristor | | | | Ratings | | | |
|---|---|---|---|---|---|---|---|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| $V_{RSM/DSM}$ | *max. non-repetitive reverse/forward blocking voltage* | | $T_{VJ}$ = 25°C | | | 1700 | V |
| $V_{RRM/DRM}$ | *max. repetitive reverse/forward blocking voltage* | | $T_{VJ}$ = 25°C | | | 1600 | V |
| $I_{R/D}$ | *reverse current, drain current* | $V_{R/D}$ = 1600 V | $T_{VJ}$ = 25°C | | | 100 | µA |
| | | $V_{R/D}$ = 1600 V | $T_{VJ}$ = 140°C | | | 10 | mA |
| $V_T$ | *forward voltage drop* | $I_T$ = 110 A | $T_{VJ}$ = 25°C | | | 1.24 | V |
| | | $I_T$ = 220 A | | | | 1.52 | V |
| | | $I_T$ = 110 A | $T_{VJ}$ = 125°C | | | 1.21 | V |
| | | $I_T$ = 220 A | | | | 1.57 | V |
| $I_{TAV}$ | *average forward current* | $T_C$ = 85°C | $T_{VJ}$ = 140°C | | | 110 | A |
| $I_{T(RMS)}$ | *RMS forward current* | 180° sine | | | | 170 | A |
| $V_{T0}$ | *threshold voltage* } *for power loss calculation only* | | $T_{VJ}$ = 140°C | | | 0.85 | V |
| $r_T$ | *slope resistance* } | | | | | 3.3 | mΩ |
| $R_{thJC}$ | *thermal resistance junction to case* | | | | | 0.3 | K/W |
| $R_{thCH}$ | *thermal resistance case to heatsink* | | | | 0.20 | | K/W |
| $P_{tot}$ | *total power dissipation* | | $T_C$ = 25°C | | | 380 | W |
| $I_{TSM}$ | *max. forward surge current* | t = 10 ms; (50 Hz), sine | $T_{VJ}$ = 45°C | | | 1.90 | kA |
| | | t = 8,3 ms; (60 Hz), sine | $V_R$ = 0 V | | | 2.05 | kA |
| | | t = 10 ms; (50 Hz), sine | $T_{VJ}$ = 140°C | | | 1.62 | kA |
| | | t = 8,3 ms; (60 Hz), sine | $V_R$ = 0 V | | | 1.75 | kA |
| $I^2t$ | *value for fusing* | t = 10 ms; (50 Hz), sine | $T_{VJ}$ = 45°C | | | 18.1 | kA²s |
| | | t = 8,3 ms; (60 Hz), sine | $V_R$ = 0 V | | | 17.5 | kA²s |
| | | t = 10 ms; (50 Hz), sine | $T_{VJ}$ = 140°C | | | 13.0 | kA²s |
| | | t = 8,3 ms; (60 Hz), sine | $V_R$ = 0 V | | | 12.7 | kA²s |
| $C_J$ | *junction capacitance* | $V_R$ = 400 V f = 1 MHz | $T_{VJ}$ = 25°C | | 95 | | pF |
| $P_{GM}$ | *max. gate power dissipation* | $t_P$ = 30 µs | $T_C$ = 140°C | | | 10 | W |
| | | $t_P$ = 300 µs | | | | 5 | W |
| $P_{GAV}$ | *average gate power dissipation* | | | | | 0.5 | W |
| $(di/dt)_{cr}$ | *critical rate of rise of current* | $T_{VJ}$ = 140°C; f = 50 Hz | repetitive, $I_T$ = 330 A | | | 150 | A/µs |
| | | $t_P$ = 200 µs; $di_G/dt$ = 0.45 A/µs; | | | | | |
| | | $I_G$ = 0.45A; $V_D$ = ⅔ $V_{DRM}$ | non-repet., $I_T$ = 110 A | | | 500 | A/µs |
| $(dv/dt)_{cr}$ | *critical rate of rise of voltage* | $V_D$ = ⅔ $V_{DRM}$ | $T_{VJ}$ = 140°C | | | 1000 | V/µs |
| | | $R_{GK}$ = ∞; method 1 (linear voltage rise) | | | | | |
| $V_{GT}$ | *gate trigger voltage* | $V_D$ = 6 V | $T_{VJ}$ = 25°C | | | 1.5 | V |
| | | | $T_{VJ}$ = -40°C | | | 1.6 | V |
| $I_{GT}$ | *gate trigger current* | $V_D$ = 6 V | $T_{VJ}$ = 25°C | | | 150 | mA |
| | | | $T_{VJ}$ = -40°C | | | 200 | mA |
| $V_{GD}$ | *gate non-trigger voltage* | $V_D$ = ⅔ $V_{DRM}$ | $T_{VJ}$ = 140°C | | | 0.2 | V |
| $I_{GD}$ | *gate non-trigger current* | | | | | 10 | mA |
| $I_L$ | *latching current* | $t_p$ = 10 µs | $T_{VJ}$ = 25°C | | | 200 | mA |
| | | $I_G$ = 0.45A; $di_G/dt$ = 0.45 A/µs | | | | | |
| $I_H$ | *holding current* | $V_D$ = 6 V $R_{GK}$ = ∞ | $T_{VJ}$ = 25°C | | | 200 | mA |
| $t_{gd}$ | *gate controlled delay time* | $V_D$ = ½ $V_{DRM}$ | $T_{VJ}$ = 25°C | | | 2 | µs |
| | | $I_G$ = 0.45A; $di_G/dt$ = 0.45 A/µs | | | | | |
| $t_q$ | *turn-off time* | $V_R$ = 100 V; $I_T$ = 110 A; $V_D$ = ⅔ $V_{DRM}$ | $T_{VJ}$ = 140°C | | 185 | | µs |
| | | di/dt = 10 A/µs; dv/dt = 20 V/µs; $t_p$ = 200 µs | | | | | |

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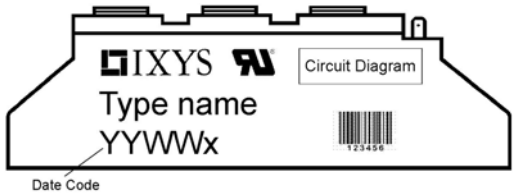
| Package TO-240AA | | | | | Ratings | | | |
|---|---|---|---|---|---|---|---|---|
| Symbol | Definition | Conditions | | | min. | typ. | max. | Unit |
| $I_{RMS}$ | *RMS current* | per terminal | | | | | 200 | A |
| $T_{stg}$ | *storage temperature* | | | | -40 | | 125 | °C |
| $T_{VJ}$ | *virtual junction temperature* | | | | -40 | | 140 | °C |
| **Weight** | | | | | | 90 | | g |
| $M_D$ | *mounting torque* | | | | 2.5 | | 4 | Nm |
| $M_T$ | *terminal torque* | | | | 2.5 | | 4 | Nm |
| $d_{Spp/App}$ | *creepage distance on surface \| striking distance through air* | | *terminal to terminal* | 13.0 | 9.7 | | | mm |
| $d_{Spb/Apb}$ | | | *terminal to backside* | 16.0 | 16.0 | | | mm |
| $V_{ISOL}$ | *isolation voltage* | t = 1 second | 50/60 Hz, RMS; $I_{ISOL}$ ≤ 1 mA | | 4800 | | | V |
| | | t = 1 minute | | | 4000 | | | V |

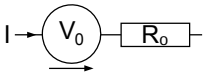



**Part number**

M = Module
C = Thyristor (SCR)
M = Thyristor
A = (up to 1800V)
110 = Current Rating [A]
P = Phase leg
1600 = Reverse Voltage [V]
TA = TO-240AA-1B

| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|---|---|---|---|---|---|
| Standard | MCMA110P1600TA | MCMA110P1600TA | Box | 6 | 513383 |

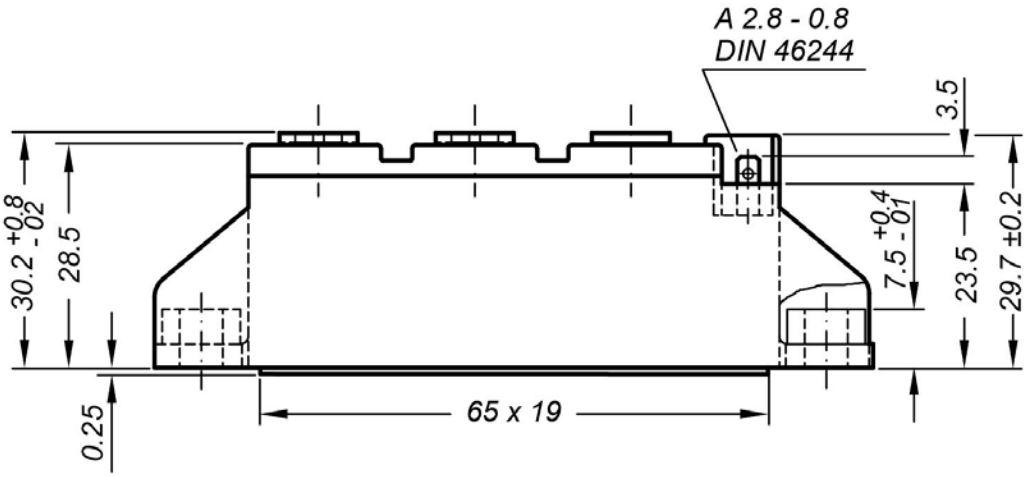
**Equivalent Circuits for Simulation** ** on die level* $T_{VJ}$ = 140°C



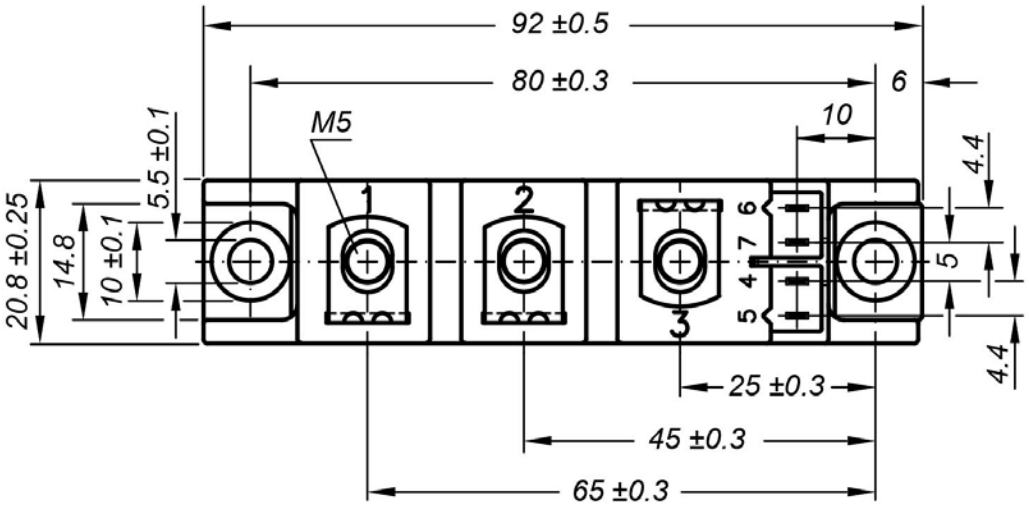

Thyristor

| | | | |
|---|---|---|---|
| $V_{0\,max}$ | *threshold voltage* | 0.85 | V |
| $R_{0\,max}$ | *slope resistance ** | 2.1 | mΩ |

## Outlines TO-240AA




General tolerance: DIN ISO 2768 class „c“




*Optional accessories: Keyed gate/cathode twin plugs*
*Wire length: 350 mm, gate = white, cathode = red*
*UL 758, style 3751*
*Type **ZY 200L** (L = Left for pin pair 4/5)*
*Type **ZY 200R** (R = Right for pin pair 6/7)*